TOSHIBA TRANSISTOR SILICON PNP TRIPLE DIFFUSED TYPE

## 2 S A 1 9 4 3

POWER AMPLIFIER APPLICATIONS

- Complementary to 2SC5200
- Recommended for 100 W High Fidelity Audio Frequency Amplifier Output Stage.

## MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V <sub>CBO</sub>	-230	V
Collector-Emitter Voltage	VCEO	-230	V
Emitter-Base Voltage	VEBO	-5	V
Collector Current	IC	-15	A
Base Current	IB	-1.5	A
Collector Power Dissipation ( $Tc = 25^{\circ}C$ )	PC	150	w
Junction Temperature	Tj	150	°C
Storage Temperature Range	T <sub>stg</sub>	$-55 \sim 150$	°C



Weight : 9.75 g (Typ.)

## ELECTRICAL CHARACTERISTICS (Ta = $25^{\circ}$ C)

CHARACTERISTIC SYMBOL TEST CONDITION MIN. TYP. MAX. UNIT Collector Cut-off Current  $V_{CB} = -230 V, I_E = 0$ **I**CBO -5.0μA \_\_\_\_ Emitter Cut-off Current  $V_{EB} = -5 V, I_C = 0$ -5.0IEBO μA Collector-Emitter Breakdown v  $V_{(BR) CEO} | I_C = -50 \text{ mA}, I_B = 0$ -230Voltage  $h_{FE}(1)$  $V_{CE} = -5 V, I_{C} = -1 A$ 55160 DC Current Gain (Note)  $V_{CE} = -5 V, I_{C} = -7 A$ 35  $h_{FE}(2)$ 60 **Collector-Emitter Saturation**  $I_{C} = -8 A, I_{B} = -0.8 A$ -1.5-3.0v VCE (sat) Voltage VBE  $V_{CE} = -5 V, I_{C} = -7 A$ v **Base-Emitter Voltage** -1.0-1.5**Transition Frequency**  $V_{CE} = -5 V, I_C = -1 A$ 30 MHz  $\mathbf{f}_{\mathbf{T}}$  $V_{CB} = -10 V, I_E = 0,$ pF Collector Output Capacitance 360 Cob f = 1 MHz

(Note) :  $h_{FE(1)}$  Classification

R: 55~110, O: 80~160

000707EAA2

00070TEAA2 TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.. The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.



000707EAA2'

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
The information contained herein is subject to change without notice.

